

ARF449A(G) ARF449B(G)

*G Denotes RoHS Compliant. Pb Free Terminal Finish.

Common
Source

RF POWER MOSFETs

N - CHANNEL ENHANCEMENT MODE

150V 90W 120MHz

The ARF449A and ARF449B comprise a symmetric pair of common source RF power transistors designed for push-pull scientific, commercial, medical and industrial RF power amplifier applications up to 120 MHz.

- **Specified 150 Volt, 81.36 MHz Characteristics:**
 - Output Power = 90 Watts.**
 - Gain = 13dB (Class C)**
 - Efficiency = 75%**
- **Low Cost Common Source RF Package.**
- **Very High Breakdown for Improved Ruggedness.**
- **Low Thermal Resistance.**
- **Nitride Passivated Die for Improved Reliability.**

MAXIMUM RATINGS

All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	ARF449A/449B(G)	UNIT
V_{DSS}	Drain-Source Voltage	450	Volts
V_{DGO}	Drain-Gate Voltage	450	
I_D	Continuous Drain Current @ $T_C = 25^\circ\text{C}$	9	Amps
V_{GS}	Gate-Source Voltage	± 30	Volts
P_D	Total Power Dissipation @ $T_C = 25^\circ\text{C}$	165	Watts
$R_{\theta JC}$	Junction to Case	0.76	$^\circ\text{C/W}$
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	$^\circ\text{C}$
T_L	Lead Temperature: 0.063" from Case for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage ($V_{GS} = 0V, I_D = 250 \mu\text{A}$)	450			Volts
$V_{DS(ON)}$	On State Drain Voltage ① ($I_{D(ON)} = 5A, V_{GS} = 10V$)			4	
I_{DSS}	Zero Gate Voltage Drain Current ($V_{DS} = V_{DSS}, V_{GS} = 0V$)			25	μA
	Zero Gate Voltage Drain Current ($V_{DS} = 0.8 V_{DSS}, V_{GS} = 0V, T_C = 125^\circ\text{C}$)			250	
I_{GSS}	Gate-Source Leakage Current ($V_{GS} = \pm 30V, V_{DS} = 0V$)			± 100	nA
g_{fs}	Forward Transconductance ($V_{DS} = 25V, I_D = 5A$)	3	5.8		mhos
$V_{GS(TH)}$	Gate Threshold Voltage ($V_{DS} = V_{GS}, I_D = 50mA$)	2		5	Volts

 **CAUTION:** These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

APT Website - <http://www.advancedpower.com>

DYNAMIC CHARACTERISTICS

ARF449A/449B(G)

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
C_{iss}	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 150V$ $f = 1\text{ MHz}$		980	1200	pF
C_{oss}	Output Capacitance			87	120	
C_{rss}	Reverse Transfer Capacitance			25	40	
$t_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$ $V_{DD} = 0.5 V_{DSS}$ $I_D = I_{D[Cont.]} @ 25^\circ C$ $R_G = 1.6\Omega$		5	10	ns
t_r	Rise Time			3.1	7	
$t_{d(off)}$	Turn-off Delay Time			15	25	
t_f	Fall Time			3	7	

FUNCTIONAL CHARACTERISTICS

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
G_{PS}	Common Source Amplifier Power Gain	$f = 81.36\text{ MHz}$ $V_{GS} = 0V$ $V_{DD} = 150V$ $P_{out} = 90W$	12	13		dB
η	Drain Efficiency		70	75		%
Ψ	Electrical Ruggedness VSWR 20:1		No Degradation in Output Power			

① Pulse Test: Pulse width < 380 μs , Duty Cycle < 2%

APT Reserves the right to change, without notice, the specifications and information contained herein.

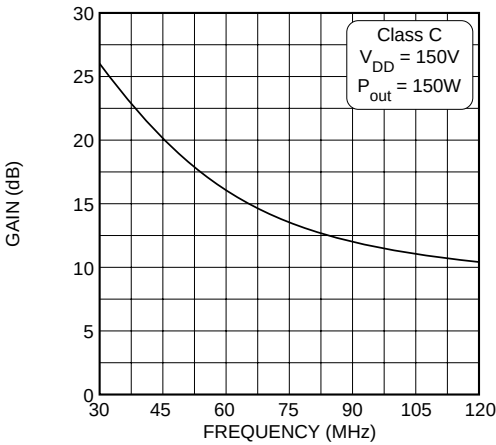


Figure 1, Typical Gain vs Frequency

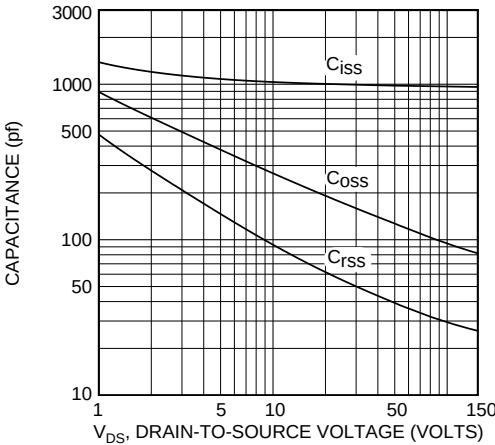


Figure 2, Typical Capacitance vs. Drain-to-Source Voltage

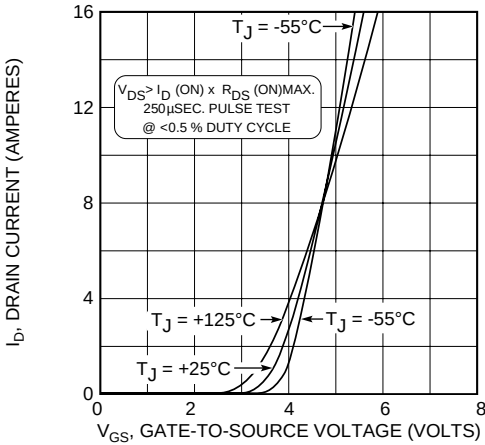


Figure 3, Typical Transfer Characteristics

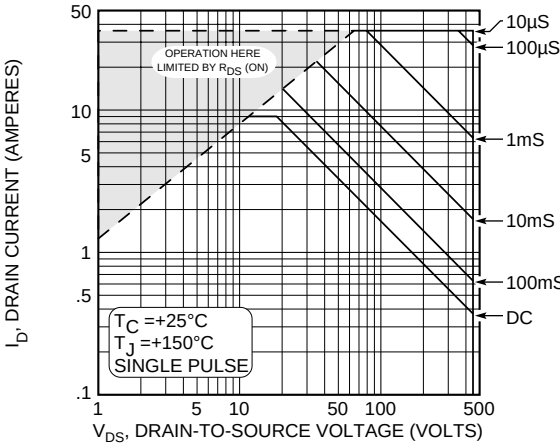


Figure 4, Typical Maximum Safe Operating Area

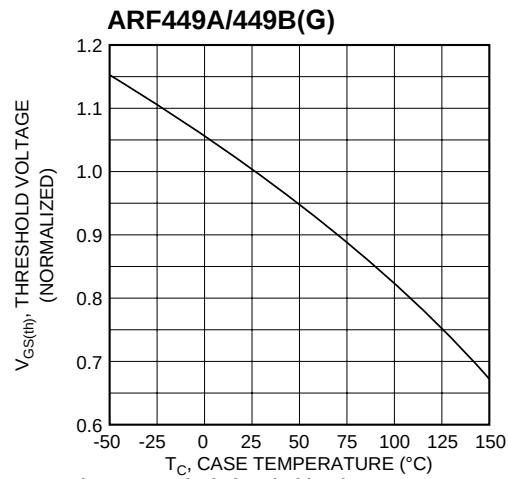


Figure 5, Typical Threshold Voltage vs Temperature

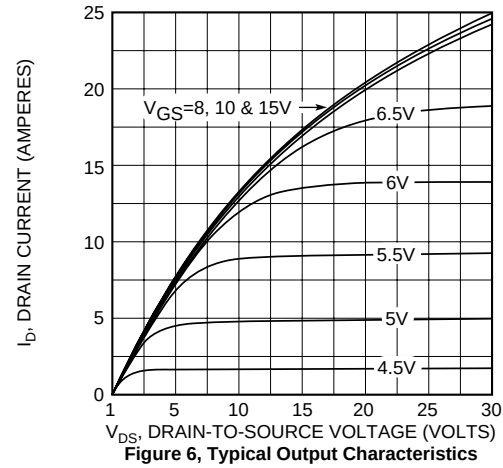


Figure 6, Typical Output Characteristics

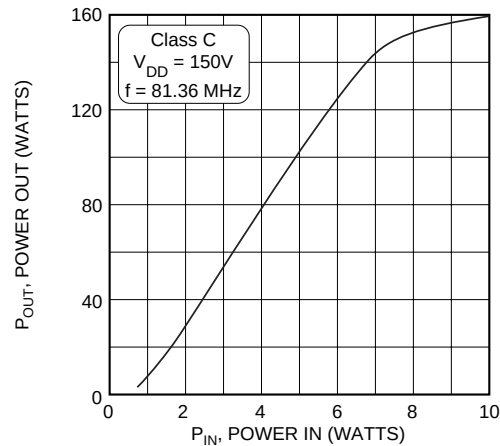


Figure 7, Typical Power Out vs Power In

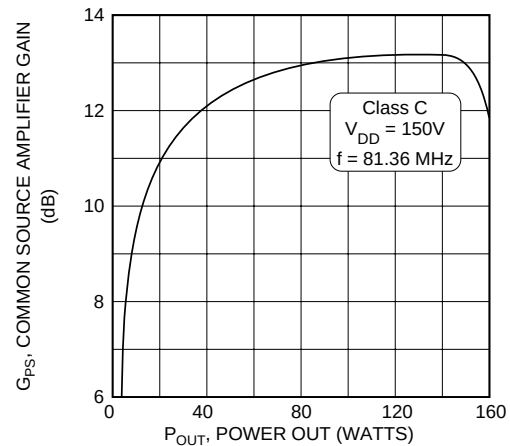


Figure 8, Typical Common Source Amplifier Gain vs Power Out

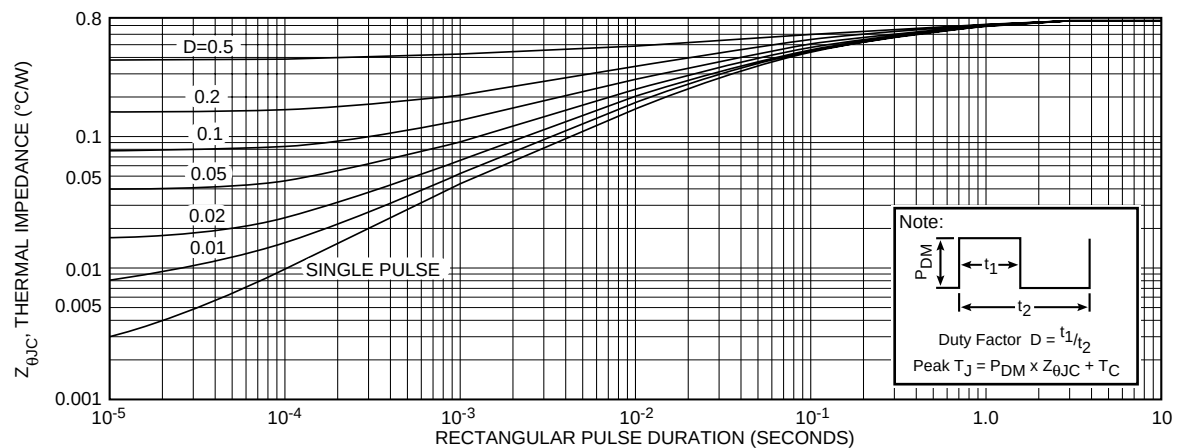


Figure 9, Typical Maximum Effective Transient Thermal Impedance, Junction-To-Case vs Pulse Duration

Table 1 - Typical Class C Large Signal Input-Output Impedance

Freq. (MHz)	Z_{in} (Ω)	Z_{OL} (Ω)
2.0	23.00 - j 7.0	93.0 - j 10
13.5	4.30 - j 9.1	63.0 - j 43
27.0	1.00 - j 4.2	32.0 - j 43
40.0	0.42 - j 1.7	17.5 - j 34
65.0	0.35 + j 1.1	7.7 - j 22
80.0	0.56 + j 2.5	5.1 - j 16
100.0	0.90 + j 3.8	3.4 - j 12

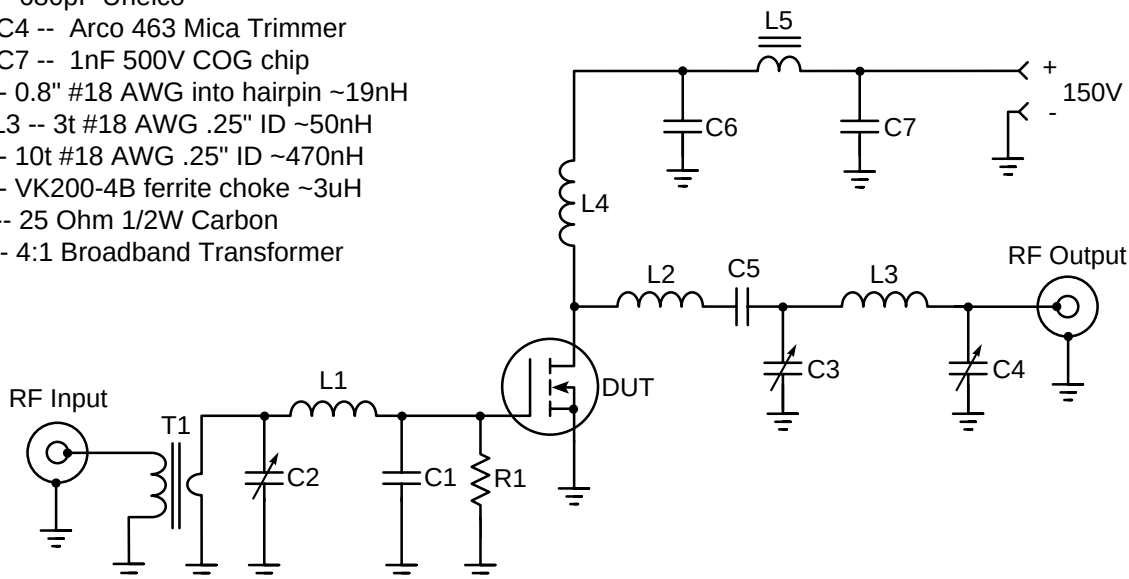
Z_{in} - gate shunted by 25 Ω

Z_{OL} - conjugate of optimum load impedance for 150W at 150V

81.36 MHz Test Circuit

Parts List

- C1 -- 680pF Unelco
 C2-C4 -- Arco 463 Mica Trimmer
 C5-C7 -- 1nF 500V COG chip
 L1 -- 0.8" #18 AWG into hairpin ~19nH
 L2-L3 -- 3t #18 AWG .25" ID ~50nH
 L4 -- 10t #18 AWG .25" ID ~470nH
 L5 -- VK200-4B ferrite choke ~3uH
 R1 -- 25 Ohm 1/2W Carbon
 T1 -- 4:1 Broadband Transformer



TO-247 Package Outline

e3 100% Sn Plated

